

Assignment3

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$$\begin{aligned}
 1. \text{ (a) } f(E_F) &= \frac{1}{1 + e^{(E_F - E_F)/kT}} = \frac{1}{2} \\
 \text{ (b) } f(E_c + kT) &= \frac{1}{1 + e^{(E_c + kT - E_c)/kT}} = \frac{1}{1 + e} = 0.269 \\
 \text{ (c) } f(E_c + kT) &= 1 - f(E_c + kT) \\
 &\Rightarrow f(E_c + kT) = \frac{1}{2} \\
 &\Rightarrow \frac{1}{1 + e^{(E_c + kT - E_F)/kT}} = \frac{1}{2} \\
 &\Rightarrow E_c + kT - E_F = 0 \\
 &\Rightarrow E_F = E_c + kT
 \end{aligned}$$

$$\begin{aligned}
 2. \text{ (a) } N_c &= 2 \left[\frac{m_n^* kT}{2\pi\hbar^2} \right]^{3/2} = 2 \left[\frac{(9.11 \times 10^{-31} \times 1.18)(0.0259 \times 1.6 \times 10^{-19})}{(2\pi)(6.63 \times 10^{-34}/2\pi)^2} \right]^{3/2} 10^{-6} \\
 &= 3.21 \times 10^{19} \text{ cm}^{-3} \cdot \text{eV} \\
 \text{ (b) } N_v &= 2 \left[\frac{m_p^* kT}{2\pi\hbar^2} \right]^{3/2} = 2 \left[\frac{(9.11 \times 10^{-31} \times 0.81)(0.0259 \times 1.6 \times 10^{-19})}{(2\pi)(6.63 \times 10^{-34}/2\pi)^2} \right]^{3/2} 10^{-6} \\
 &= 1.83 \times 10^{19} \text{ cm}^{-3} \cdot \text{eV}
 \end{aligned}$$

$$\begin{aligned}
 3. \text{ (a) } n = p = n_i &= 10^{10} \text{ cm}^{-3} \\
 \text{ (b) } \text{ Since } N_D &\ll N_A, N_D \ll n_i \\
 n &\approx N_D = 10^{13} \text{ cm}^{-3} \\
 p &\approx n_i^2 / N_D = 10^7 \text{ cm}^{-3} \\
 \text{ (c) } \text{ Since } N_A &\ll N_D, N_A \ll n_i \\
 n &\approx N_D = 10^{17} \text{ cm}^{-3}
 \end{aligned}$$

$$p \approx n_i^2/N_D = 10^3 \text{ cm}^{-3}$$

$$(d) \ p = \frac{N_A - N_D}{2} + \left[\left(\frac{N_A - N_D}{2} \right)^2 + n_i^2 \right]^{1/2} \approx N_A - N_D = 2 \times 10^{17} \text{ cm}^{-3}$$

$$n = n_i^2/p = 5 \times 10^2 \text{ cm}^{-3}$$

$$(e) \ E_i = \frac{E_c + E_v}{2} + \frac{3}{4}kT \ln \left(\frac{m_p^*}{m_n^*} \right) = \frac{E_c + E_v}{2} - 0.0073$$

$$E_i - E_F = kT \ln N_A/n_i = 0.0259 \ln(10^{17}/10^{10}) = 0.417$$

$$\text{Then } E_F = E_i - 0.47 = \frac{E_c + E_v}{2} - 0.4243$$

Assume $E_v = 0$, which implies $E_c = E_G$

$$E_F = \frac{E_G}{2} - 0.4243 = \frac{1.12}{2} - 0.4243 = 0.1357 \text{ eV} > E_v + 3kT$$

So E_F is in the nondegenerate area.

4. From $E_i = \frac{E_c + E_v}{2} + \frac{3}{4}kT \ln \left(\frac{m_p^*}{m_n^*} \right)$ and $E_G = E_c - E_v$, we can derive that

$$E_i - E_v = \frac{E_G}{2} + \frac{3}{4}kT \ln \left(\frac{m_p^*}{m_n^*} \right)$$

$$E_c - E_i = \frac{E_G}{2} + \frac{3}{4}kT \ln \left(\frac{m_p^*}{m_n^*} \right)$$

(a) Si at 300K with $m_n^* = 1.182m_0$ and $m_p^* = 0.81m_0$

$$E_i - E_v = 0.5527 \text{ eV}$$

$$E_c - E_v = 0.5673 \text{ eV}$$

(b) GaAs at 300K with $m_n^* = 0.067m_0$ and $m_p^* = 0.524m_0$

$$E_i - E_v = 0.67 \text{ eV}$$

$$E_c - E_v = 0.75 \text{ eV}$$

5. (a)

(b) E_i will lie above the midgap.

Because DOS is smaller in the conduction band, equal number of states in two bands can be filled only if E_i lies close to E_c .

$$(c) E_i = \frac{E_c + E_v}{2} + \frac{3}{4}kT \ln \left(\frac{m_p^*}{m_n^*} \right) = \frac{E_c + E_v}{2} + 0.04$$

So E_i lies 0.04eV above the midgap.

$$(d) N_c = 2 \left[\frac{m_n^* kT}{2\pi\hbar^2} \right]^{3/2} = 4.26 \times 10^{17} \text{ cm}^{-3}$$

$$N_v = 2 \left[\frac{m_p^* kT}{2\pi\hbar^2} \right]^{3/2} = 9.41 \times 10^{18} \text{ cm}^{-3}$$

For nondegenerate semiconductors

$$E_v + 3kT \leq E_F \leq E_c - 3kT$$

$$n = N_c e^{(E_F - E_c)/kT} \leq N_c e^{-3}$$

$$p = N_v e^{(E_v - E_F)/kT} \leq N_v e^{-3}$$

Also, for n -type GaAs, $n \approx N_D$; for p -type GaAs, $p \approx N_A$. Then

$$(N_D)_{max} \approx N_c e^{-3} = 2.21 \times 10^{16} \text{ cm}^{-3}$$

$$(N_A)_{max} \approx N_v e^{-3} = 4.68 \times 10^{17} \text{ cm}^{-3}$$